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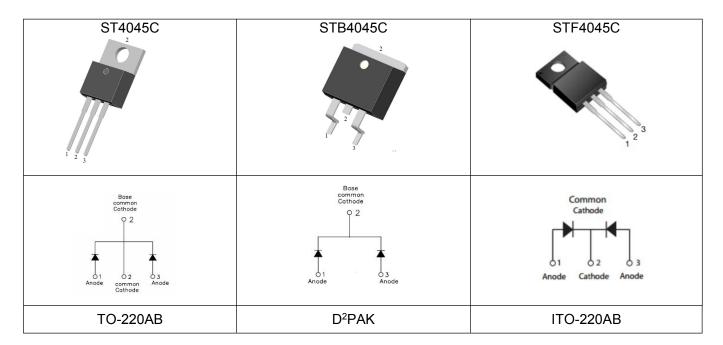
# ST4045C/STB4045C/STD4045C SCHOTTKY RECTIFIER

### **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

#### **Features**

- 150 °C T<sub>J</sub> operation
- Center tap configuration
- Ultralow forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Trench MOS Schottky technology
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	45	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @Tc=105°C, rectangular wave form	20(Per Leg) 40(Per Device)	Α
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I <sub>FSM</sub>	8.3ms, Half Sine pulse	240	Α

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#### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	V <sub>F1</sub>	@ 5A, Pulse, T <sub>J</sub> = 25°C	0.39	-	
		@ 10A, Pulse, T <sub>J</sub> = 25℃	0.43	-	V
		@ 20A, Pulse, T₁= 25°C	0.50	0.58	
	$V_{F2}$	@ 5A, Pulse, T <sub>J</sub> = 125℃	0.26	-	
		@ 10A, Pulse, T <sub>J</sub> = 125℃	0.31	-	V
		@ 20A, Pulse, T <sub>J</sub> = 125°C	0.41	0.50	
Reverse Current(Per Leg)*	I <sub>R1</sub>	$@V_R = \text{rated } V_R$ $T_J = 25^{\circ}C$	0.21	3.0	mA
	I <sub>R2</sub>	$@V_R = \text{rated } V_R$ $T_J = 125 ^{\circ}C$	116	150	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	868	-	pF

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

### **Thermal-Mechanical Specifications:**

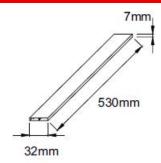
Characteristics	Symbol	ST4045C	STB4045C	STF4045C	Units
Junction Temperature	TJ		-55 to +150		°C
Storage Temperature	T <sub>stg</sub>		-55 to +150		°C
Typical Thermal Resistance Junction to Case(Per Leg)	R <sub>eJC</sub>	1.6	1.6	5	°C/W

# **Tube Specification**

Device	Package	Weight	Shipping
ST4045C	TO-220AB	2.0	50pcs / tube
STB4045C	D <sup>2</sup> PAK	1.85	800pcs / reel
STF4045C	ITO-220AB	2.0	50pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

## **Tube Specification(TO-220AB/ITO-220AB)**



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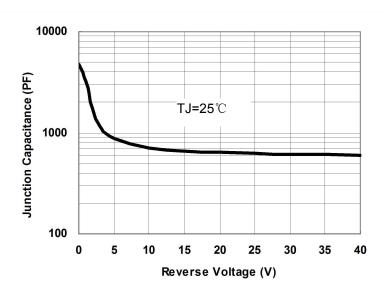
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### **Ratings and Characteristics Curves**



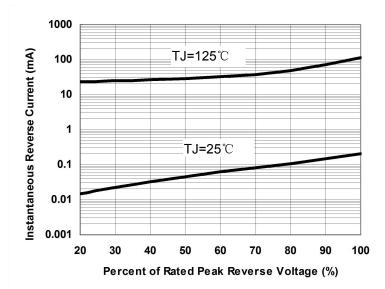


Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

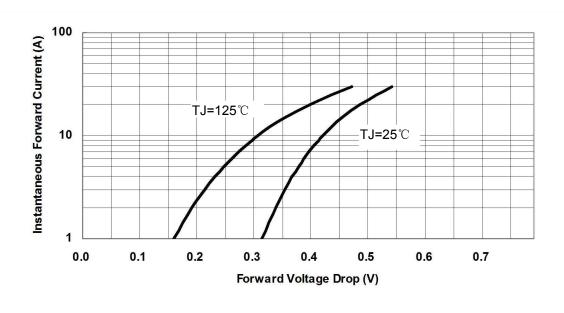


Fig.3-Typical Instantaneous Forward Voltage Characteristics

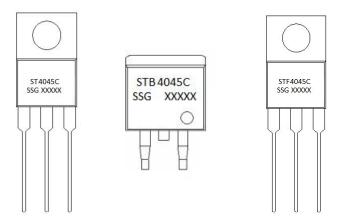
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# **Marking Diagram**



#### Where XXXXX is YYWWL

 ST
 = Device Type

 B/F
 = Package type

 40
 = Forward Current (40A)

 45
 = Reverse Voltage (45V)

 C
 = Configuration

 SSG
 = SSG

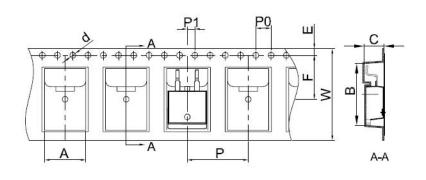
 YY
 = Year

 WW
 = Week

 L
 = Lot Number

**Cautions:** Molding resin Epoxy resin UL:94V-0

### **Carrier Tape Specification D2PAK**



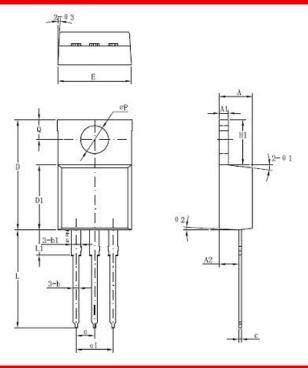
SYMBOL	Millimeters		
STWIDOL	Min.	Max.	
Α	10.70	10.90	
В	16.03	16.23	
С	5.11	5.31	
d	1.45	1.65	
Е	1.65	1.85	
F	11.40	11.60	
P0	3.90	4.10	
Р	15.90	16.10	
P1	1.90	2.10	
W	23.90	24.30	





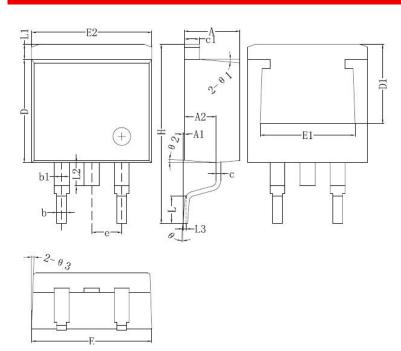


### **Mechanical Dimensions TO-220AB**



Symbol	Dimensions in millimeters				
	Min	Typical	Max		
Α	4.42	4.57	4.72		
A1	1.17	1.27	1.37		
A2	2.52	2.69	2.89		
b	0.71	0.81	0.96		
b1	1.17	1.27	1.37		
С	0.31	0.38	0.61		
D	14.94	15.24	15.54		
D1	8.85	9.00	9.15		
Е	10.01	10.16	10.31		
е		2.54			
e1	4.98	5.06	5.18		
H1	6.04	6.24	6.44		
L	12.7	13.56	13.80		
L1	3.56	3.5	3.96		
ФР	3.74	3.84	4.04		
Q	2.54	2.74	2.94		
Θ1		7°			
Θ2		3°			
Θ3		4°			

### **Mechanical Dimensions D<sup>2</sup>PAK**



	Dimensions in millimeters				
Symbol	Min.	Typical	Max.		
Α	4.55	4.70	4.85		
A1	0	0.10	0.25		
A2	2.59	2.69	2.89		
b	0.71	0.81	0.96		
b1		1.27			
С	0.36	0.38	0.61		
c1	1.17	1.27	1.37		
D	8.55	8.70	8.85		
D1	6.40				
E	10.01	10.16	10.31		
E1	7.6				
E2	9.98	10.08	10.18		
е		2.54			
Н	14.6	15.1	15.6		
L	2.00	2.30	2.70		
L1	1.17	1.27	1.40		
L2			2.20		
L3		0.25BSC			
е	0	-	8°		
e1		5°			
e2		4°			
e3		4°			

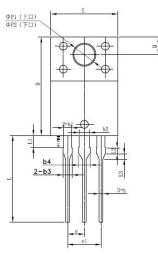
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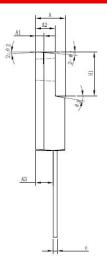






# **Mechanical Dimensions ITO-220AB**







	Dimensions in millimeters			
Symbol	Min.	Typical	Max.	
Α	4.30	4.50	4.70	
A1	1.10	1.30	1.50	
A2	2.80	3.00	3.20	
A3	2.50	2.70	2.90	
b	0.50	0.60	0.75	
b1	1.10	1.20	1.35	
b2	1.50	1.60	1.75	
b3	1.20	1.30	1.45	
b4	1.60	1.70	1.85	
С	0.50	0.60	0.75	
D	14.80	15.00	15.20	
E	9.96	10.16	10.36	
е		2.55		
e1		5.10		
H1	6.50	6.70	6.90	
L	12.70	13.20	13.70	
L1	1.60	1.80	2.00	
L2	0.80	1.00	1.20	
L3	0.60	0.80	1.00	
ΦP1(上口)	3.30	3.50	3.70	
ΦP2(下口)	2.99	3.19	3.39	
Q	2.50	2.70	2.90	
Θ1		5°		
Θ2		4°		
Θ3		10°		
Θ4		5°		
Θ5		5°		







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